

19-1825; Rev 0; 10/00

EVALUATION KIT MANUAL FOLLOWS DATA SHEET



2.4GHz Monolithic Voltage-Controlled Oscillators

General Description

The MAX2750/MAX2751/MAX2752 are self-contained voltage-controlled oscillators (VCOs) intended for use in the 2.4GHz to 2.5GHz ISM band. Each IC combines a fully integrated oscillator and output buffer in a miniature 8-pin μ MAX package.

The inductor and varactor elements of the tank are integrated on-chip, greatly simplifying application of the part. The only required external components are a couple of supply bypass capacitors. The IC provides direct connection to the VCO tuning voltage input and the VCO buffer output. The tuning voltage input range is $\pm 0.4V$ to $\pm 2.4V$, and the oscillator frequency tuning range is factory adjusted to provide guaranteed limits. The output signal is buffered by an amplifier stage (internally matched to 50Ω) to provide higher output power and isolate the device from load impedance variations.

The MAX2750/MAX2751/MAX2752 operate over a +2.7V to +5.5V supply voltage range. Internal regulation of the oscillator supply voltage eliminates the need for an external LDO regulator for the VCO. The IC also provides a digitally controlled shutdown mode to permit implementation of sophisticated power-supply management. In shutdown, the supply current is reduced to less than 1μ A.

Applications

802.11b DSSS WLAN 802.11 FHSS WLAN Home RF 2.4GHz Bluetooth ISM Proprietary Radio Guaranteed Frequency Tuning Range MAX2750: 2400MHz to 2500MHz (Zero IF) MAX2751: 2120MHz to 2260MHz (240MHz to 280MHz IF) MAX2752: 2025MHz to 2165MHz (335MHz to 375MHz IF)

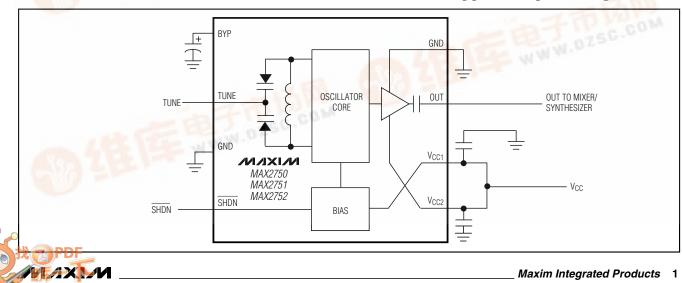
- On-Chip Tank Circuit
- Internally Matched Output Buffer Amplifier
- Low-Current Shutdown Mode
- +2.7V to +5.5V Supply Voltage Range
- Miniature 8-Pin µMAX Package

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX2750EUA	-40°C to +85°C	8 µMAX
MAX2751EUA	-40°C to +85°C	8 µMAX
MAX2752EUA	-40°C to +85°C	8 µMAX

Pin Configuration appears at end of data sheet.

Typical Operating Circuit



_Features

ABSOLUTE MAXIMUM RATINGS

V_{CC} to <u>GND</u>.....-0.3V to +6V TUNE, <u>SHDN</u>, BYP, OUT to GND.....-0.3V to (V_{CC} + 0.3V) Continuous Power Dissipation (T_A = +70°C) 8-Pin μ MAX (derate 5.7mW/°C above T_A = +70°C).....457mW Operating Temperature Range-40°C to +85°C Junction Temperature+150°C Storage Temperature Range-65°C to +150°C Lead Temperature (soldering, 10s)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $(V_{CC} = +2.7V \text{ to } +5.5V, V_{TUNE} = +0.4V \text{ to } +2.4V, V_{SHDN} \le +2V, OUT = \text{connected to } 50\Omega \text{ load}, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}.$ Typical values are at $V_{CC} = +3.0V, T_A = +25^{\circ}\text{C}$, unless otherwise noted.) (Note 1)

PARAMETER	CONDITIONS		MIN	ТҮР	MAX	UNITS
Supply Voltage			2.7		5.5	V
	MAX2750	$T_A = +25^{\circ}C$		11.3	14.4	mA
	WAX2750	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		14.1	17.0	
Cueshy Current		$T_A = +25^{\circ}C$		9.7	12.1	
Supply Current	MAX2751	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		12.7	15.9	
	MAX2752	$T_A = +25^{\circ}C$		10	12.1	
		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		12.8	15.2	
Shutdown Supply Current				0.2	1	μA
SHDN Input Voltage Low					0.6	V
SHDN Input Voltage High			2.0			V
SHDN Input Current Low	V <u>SHDN</u> ≤ 0.6V		-2		2	μA
SHDN Input Current High	V _{SHDN} ≥ 2.0V		-2		2	μA
TUNE Input Current	$0.4 \le V_{TUNE} \le 2.4V$			0.02		nA

AC ELECTRICAL CHARACTERISTICS

(MAX2750/MAX2751/MAX2752 EV kit, V_{CC} = +2.7V to +5.5V, V_{TUNE} = +0.4V to +2.4V, V_{SHDN} \leq +2V, OUT = connected to 50 Ω load, T_A = +25°C. Typical values are at V_{CC} = +3.0V, unless otherwise noted.)

PARAMETER	CONDITIONS		MIN	ТҮР	МАХ	UNITS
	$V_{TUNE} = +0.4V \text{ to } +2.4V,$ $T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$	MAX2750	2400		2500	MHz
Oscillator Guaranteed Frequency Limits (Note1)		MAX2751	2120		2260	MHz
		MAX2752	2025		2165	MHz
Phase Noise	foffset = 4MHz	·		-125		dBc/Hz
Flase Noise	Noise floor			-151		dBm/Hz
	MAX2750	$f_{OSC} = 2400 MHz, +3V$		140		MHz/V
		f _{OSC} = 2500MHz, +3V		90		
Turing Cain (Nate 0)	MAX2751	f _{OSC} = 2120MHz, +3V		175		
Tuning Gain (Note 2)		f _{OSC} = 2260MHz, +3V		110		
		f _{OSC} = 2025MHz, +3V		170		
	MAX2752	f _{OSC} = 2165MHz, +3V		105		
Output Power		•	Ì	-3		dBm
Return Loss				12		dB
Harmonics				-30		dBc



AC ELECTRICAL CHARACTERISTICS (continued)

(MAX2750/MAX2751/MAX2752 EV kit, V_{CC} = +2.7V to +5.5V, V_{TUNE} = +0.4V to +2.4V, V_{SHDN} \leq +2V, OUT = connected to 50 Ω load, T_A = +25°C. Typical values are at V_{CC} = +3.0V, unless otherwise noted.)

PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNITS
Load Pulling	VSWR = 2:1, all phases		4		MHzp-p
Supply Pushing	V _{CC} stepped: +3.3V to +2.8V		1.3		MHz/V
Oscillator Turn-On Time (Note 3)	Exiting shutdown		8		μs
Oscillator Turn-Off Time (Note 4)	Entering shutdown		5		μs

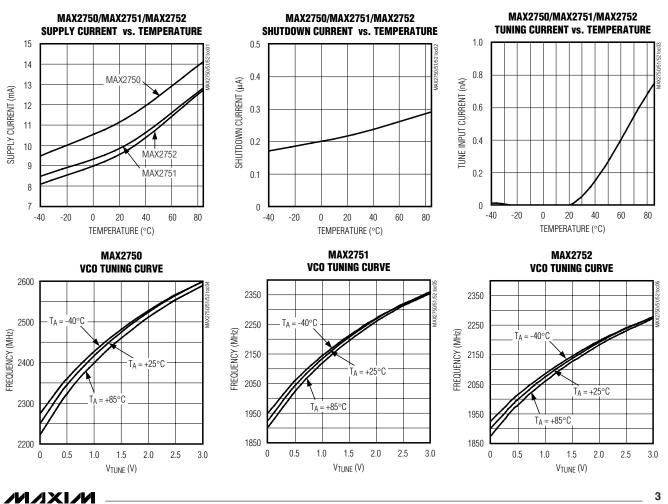
Note 1: Specifications are production tested at $T_A = +25^{\circ}C$. Limits over temperature are guaranteed by design and characterization. Note 2: Tuning gain is measured at the oscillator's guaranteed frequency limits.

Note 3: Turn-on time to within 3dB of final output power

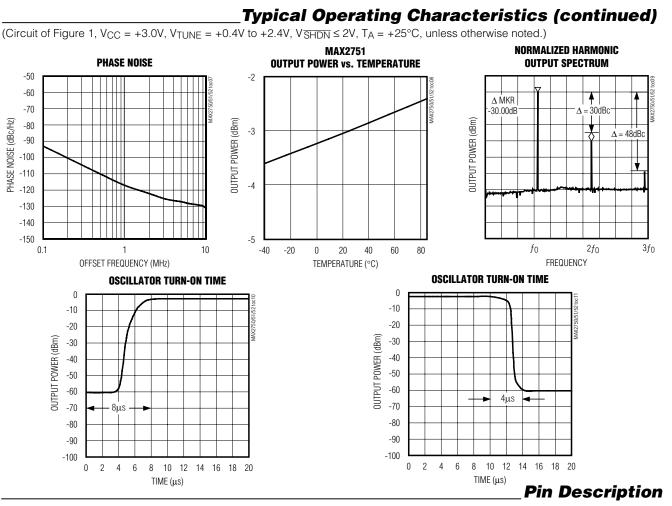
Note 4: Turn-off time to output power of -10dBm.

Typical Operating Characteristics

(Circuit of Figure 1, V_{CC} = +3.0V, V_{TUNE} = +0.4V to +2.4V, $V_{\overline{SHDN}} \le 2V$, T_A = +25°C, unless otherwise noted.)



MAX2750/MAX2751/MAX2752



PIN	NAME	FUNCTION
1	BYP	VCO Bypass. Bypass with a 0.1µF capacitor to GND.
2 TUNE Oscillator Frequency Tuning Voltage Input. High-impedance input with a voltage input range (low frequency) to +2.4V (high frequency).		Oscillator Frequency Tuning Voltage Input. High-impedance input with a voltage input range of +0.4V (low frequency) to +2.4V (high frequency).
3 GND Ground Connection for Oscillator and Biasing. Requires a low-inductance connection to the c board ground plane.		Ground Connection for Oscillator and Biasing. Requires a low-inductance connection to the circuit board ground plane.
4	SHDN	Shutdown Logic Input. A high-impedance input logic level low disables the device and reduces supply current to less than 1.0µA. A logic level high enables the device.
5	V _{CC1}	Bias and Oscillator DC Supply Voltage Connection. Bypass separately from PIN6 with a 220pF capacitor to GND for low noise and low spurious content performance from the oscillator.
6	V _{CC2}	Output Buffer DC Supply Voltage Connection. Bypass separately from PIN5 with a 220pF capacitor to GND for best high frequency performance.
7	OUT	Buffered Oscillator Output. Incorporates an internal DC blocking capacitor. OUT is internally matched to 50Ω .
8	GND	Ground Connection for Output Buffer. Requires a low-inductance connection to the circuit board ground plane.
4	·	N/IXI/N

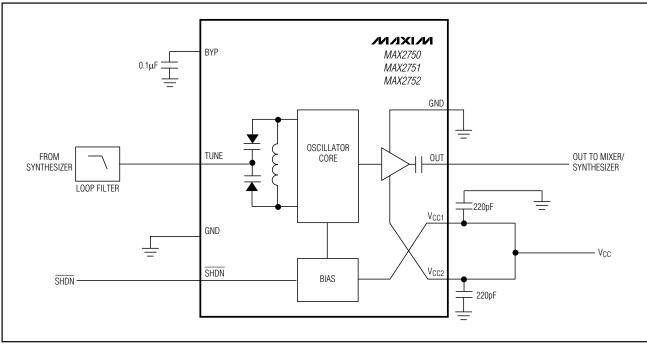


Figure 1. Typical Application Circuit

Detailed Description

Oscillator

The MAX2750/MAX2751/MAX2752 VCOs are implemented as an LC oscillator topology, integrating all of the tank components on-chip. This fully monolithic approach provides an extremely easy-to-use VCO, equivalent to a VCO module. The frequency is controlled by a voltage applied to the TUNE pin, which is internally connected to the varactor. The VCO core uses a differential topology to provide a stable frequency versus supply voltage and improve the immunity to load variations. In addition, there is a buffer amplifier following the oscillator core to provide added isolation from load variations and to boost the output power.

Output Buffer

The oscillator signal from the core drives an output buffer amplifier. The amplifier is internally matched to 50Ω including an on-chip DC blocking capacitor. No external DC blocking capacitor is required, eliminating the need for any external components. The output amplifier has its own V_{CC} and GND pins to minimize load-pulling effects. The amplifier boosts the oscillator signal to a level suitable for driving most RF mixers.

Applications Information

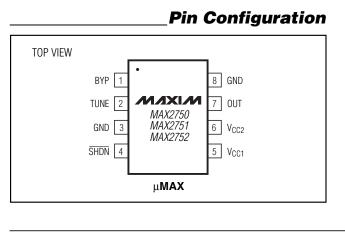
Tune Input

The tuning input is typically connected to the output of the PLL loop filter. The loop filter provides an appropriately low-impedance source. The input may incorporate an extra RC filter stage to reduce high-frequency noise and spurious signals. Any excess noise on the tuning input is directly translated into FM noise, which can degrade the phase-noise performance of the oscillator. Therefore, it is important to minimize the noise introduced on the tuning input. A simple RC filter with low corner frequency is needed during testing in order to filter the noise present on the voltage source driving the tuning line.

Layout Issues

Always use controlled impedance lines (microstrip, coplanar waveguide, etc.) for high-frequency signals. Always place decoupling capacitors as close to the V_{CC} pins as possible; for long V_{CC} lines, it may be necessary to add additional decoupling capacitors located further from the device. Always provide a low-inductance path to ground, and keep GND vias as close to the device as possible. Thermal reliefs on GND pads are not recommended.

MAX2750/MAX2751/MAX2752



Chip Information

TRANSISTOR COUNT: 176 PROCESS: BiPOLAR

Package Information

